

DMN3009LFV

#### 30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (Type UX)

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>C</sub> = +25°C
	5.5mΩ @ V <sub>GS</sub> = 10V	60A
30V	9.0mΩ @ V <sub>GS</sub> = 4.5V	50A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

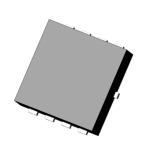
#### **Features and Benefits**

- Low R<sub>DS(ON)</sub> ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

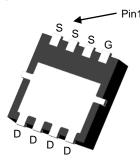
#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)

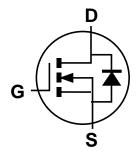
#### PowerDI3333-8 (Type UX)







**Bottom View** 



**Equivalent Circuit** 

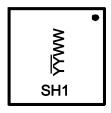
#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3009LFV-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel
DMN3009LFV-13	PowerDI3333-8 (Type UX)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



SH1= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	$V_{DSS}$	30	V	
Gate-Source Voltage	$V_{GSS}$	±20	V	
Continuous Drain Current (Note 7) V <sub>GS</sub> = 10V	$T_C = +25$ °C $T_C = +70$ °C	ID	60 50	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	90	А	
Maximum Continuous Body Diode Forward Current (Note 7)		Is	60	Α
Avalanche Current, L = 0.1mH (Note 8)		I <sub>AS</sub>	33	Α
Avalanche Energy, L = 0.1mH (Note 8)	E <sub>AS</sub>	58	mJ	

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		$P_D$	1.0	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ hetaJA}$	126	°C/W
Total Power Dissipation (Note 6)		$P_{D}$	2.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ hetaJA}$	62	°C/W
Thermal Resistance, Junction to Case (Note 7)		$R_{ heta JC}$	3.5	C/VV
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V$ , $I_{D} = 250 \mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	_	1	μΑ	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	1	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	3	٧	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance			3.5	5.5	mΩ	$V_{GS} = 10V, I_D = 30A$	
Static Dialii-Source Off-Resistance	R <sub>DS(ON)</sub>	-	4.6	9.0	11122	$V_{GS} = 4.5V, I_{D} = 15A$	
Diode Forward Voltage	$V_{SD}$	1	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C <sub>iss</sub>	-	2,000	_	pF	., .=., .,	
Output Capacitance	Coss	_	315	_	pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, - f = 1MHz	
Reverse Transfer Capacitance	Crss	1	247		рF	11 = 11VID2	
Gate Resistance	$R_g$	1	2.2	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_g$	l	20	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_g$		42	_	nC	\/ 45\/ L 45\	
Gate-Source Charge	$Q_{gs}$	1	4.7	_	nC	$V_{DS} = 15V, I_{D} = 15A$	
Gate-Drain Charge	$Q_{gd}$	-	7.4	_	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.9	_	ns		
Turn-On Rise Time	t <sub>R</sub>	_	4.1	_	ns	$V_{DD} = 15V, V_{GS} = 10V,$ $R_G = 3.3\Omega, , I_D = 15A$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	31	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	15	_	ns		
Body Diode Reverse Recovery Time	t <sub>RR</sub>	-	15	_	ns	1 45A -11/-11 400A/	
Body Diode Reverse Recovery Charge	$Q_{RR}$	_	6.0	_	nC	$I_F = 15A$ , di/dt = 100A/µs	

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

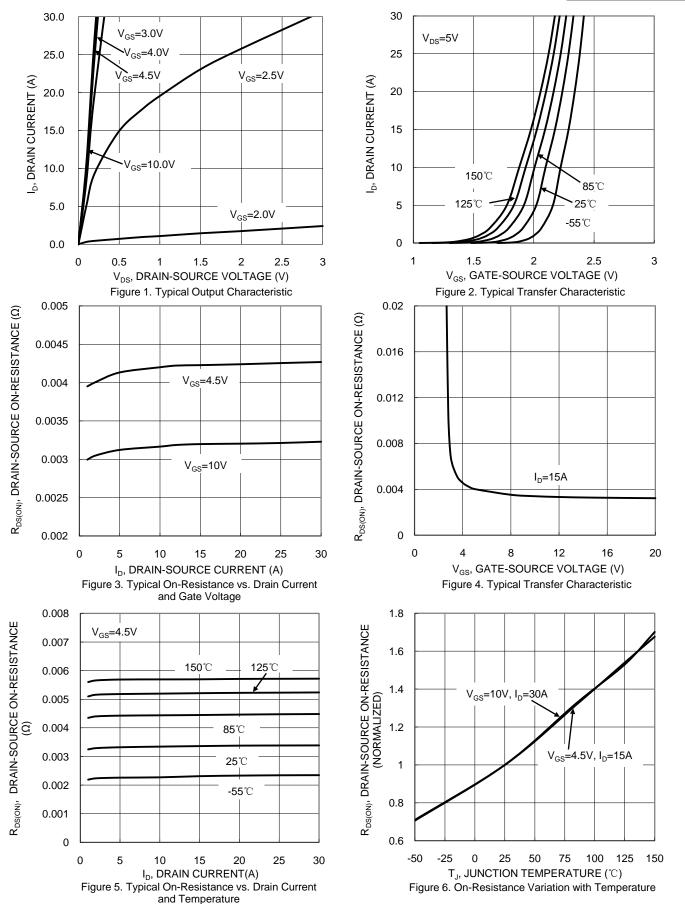
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .
- S. Short duration pulse test used to minimize self-heating effect.
  Guaranteed by design. Not subject to product testing.



March 2017

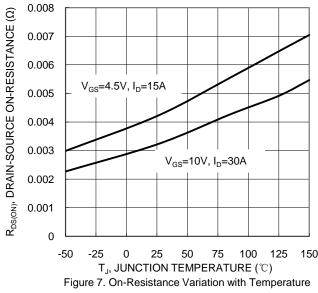
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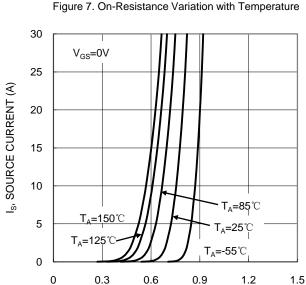




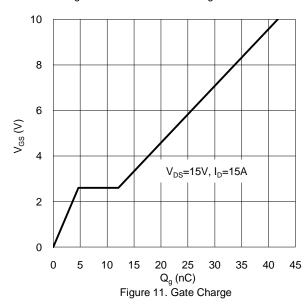






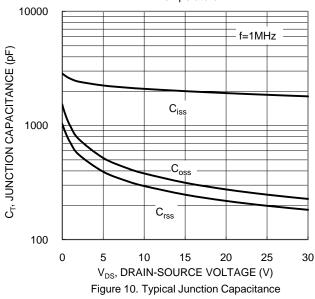


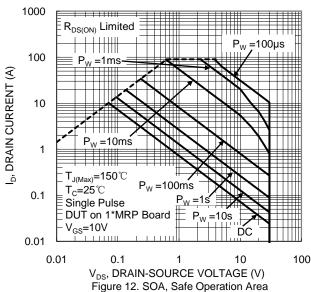
V<sub>SD</sub>, SOURCE-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current



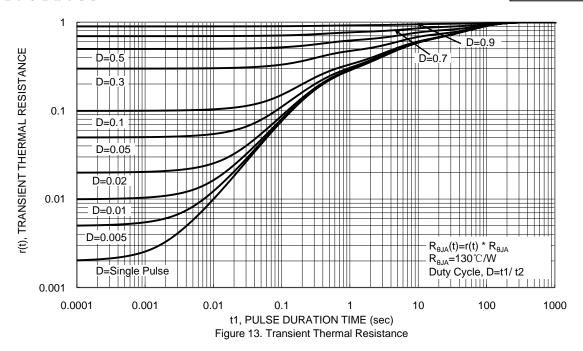
2  $V_{GS(TH)}, \, GATE \, THRESHOLD \, VOLTAGE \, (V)$ 1.7 I<sub>D</sub>=1mA 1.4 1.1  $I_D=250\mu A$ 8.0 0.5 0.2 -50 -25 25 50 75 100 125  $T_J$ , JUNCTION TEMPERATURE ( $^{\circ}$ C)

Figure 8. Gate Threshold Variation vs. Junction Temperature







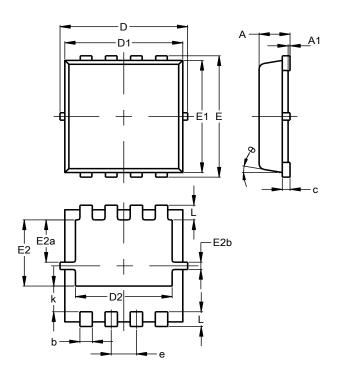




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (Type UX)

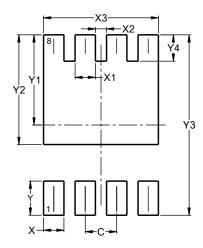


PowerDI3333-8 (Type UX)				
Dim			Тур	
Α	0.75	0.85	0.80	
A1	0.00	0.05		
b	0.25	0.40	0.32	
С	0.10	0.25	0.15	
D	3.20	3.40	3.30	
D1	2.95	3.15	3.05	
D2	2.30	2.70	2.50	
Е	3.20	3.40	3.30	
E1	2.95	3.15	3.05	
E2	1.60	2.00	1.80	
E2a	0.95	1.35	1.15	
E2b	0.10	0.30	0.20	
е	0.65 BSC			
k	0.50	0.90	0.70	
L	0.30	0.50	0.40	
θ	0°	12°	10°	
All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)		
С	0.650		
X	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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